

Precision CMOS Analog Switches

DESCRIPTION

The DG417, DG418, DG419 monolithic CMOS analog switches were designed to provide high performance switching of analog signals. Combining low power, low leakages, high speed, low on-resistance and small physical size, the DG417 series is ideally suited for portable and battery powered industrial and military applications requiring high performance and efficient use of board space.

To achieve high-voltage ratings and superior switching performance, the DG417 series is built on Vishay Siliconix's high voltage silicon gate (HVSG) process. Break-before-make is guaranteed for the DG419, which is an SPDT configuration. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG417 and DG418 respond to opposite control logic levels as shown in the Truth Table.

FEATURES

- ± 15 V analog signal range
- On-resistance - $R_{DS(on)}$: 20 Ω
- Fast switching action - t_{ON} : 100 ns
- Ultra low power requirements - P_D : 35 nW
- TTL and CMOS compatible
- MiniDIP and SOIC packaging
- 44 V supply max. rating
- 44 V supply max. rating
- Compliant to RoHS directive 2002/95/EC



RoHS*
COMPLIANT

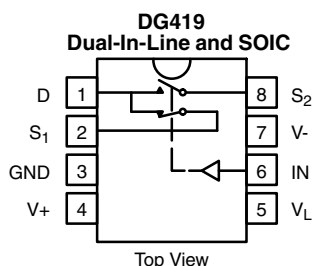
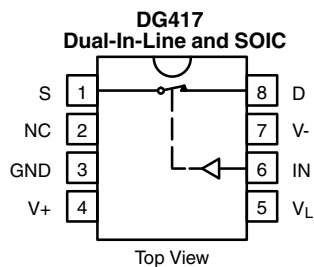
BENEFITS

- Wide dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- Improved reliability

APPLICATIONS

- Precision test equipment
- Precision instrumentation
- Battery powered systems
- Sample-and-hold circuits
- Military radios
- Guidance and control systems
- Hard disk drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	DG417	DG418
0	ON	OFF
1	OFF	ON

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V

TRUTH TABLE DG419

Logic	SW ₁	SW ₂
0	ON	OFF
1	OFF	ON

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply



ORDERING INFORMATION		
Temp. Range	Package	Part Number
DG417, DG418		
- 40 °C to 85 °C	8-Pin Plastic MiniDIP	DG417DJ DG417DJ-E3
		DG418DJ DG418DJ-E3
	8-Pin Narrow SOIC	DG417DY DG417DY-E3 DG417DY-T1 DG417DY-T1-E3
		DG418DY DG418DY-E3 DG418DY-T1 DG418DY-T1-E3
DG419		
- 40 °C to 85 °C	8-Pin Plastic MiniDIP	DG419DJ DG419DJ-E3
	8-Pin Narrow SOIC	DG419DY DG419DY-E3 DG419DY-T1 DG419DY-T1-E3

ABSOLUTE MAXIMUM RATINGS			
Parameter (Voltages referenced to V-)	Limit	Unit	
V+	44	V	
GND	25		
V _L	(GND - 0.3) to (V+) + 0.3		
Digital Inputs ^a , V _S , V _D	(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first		
Current, (Any Terminal) Continuous	30	mA	
Current, S or D (Pulsed at 1 ms, 10 % Duty Cycle)	100		
Storage Temperature	(AK Suffix)	- 65 to 150	°C
	(DJ, DY Suffix)	- 65 to 125	
Power Dissipation (Package) ^b	8-Pin Plastic MiniDIP ^c	400	mW
	8-Pin Narrow SOIC ^d	400	
	8-Pin CerDIP ^e	600	

Notes:

- a. Signals on S_x, D_x, or I_{Nx} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 75 °C.
- d. Derate 6.5 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.

SCHEMATIC DIAGRAM Typical Channel


Figure 1.

SPECIFICATIONS^a										
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}$, $V_- = -15\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f	Temp. ^b	Typ. ^c	A Suffix -55 °C to 125 °C		D Suffix -40 °C to 85 °C		Unit	
					Min. ^d	Max. ^d	Min. ^d	Max. ^d		
Analog Switch										
Analog Signal Range ^e	V_{ANALOG}		Full		-15	15	-15	15	V	
Drain-Source On-Resistance	$R_{DS(on)}$	$I_S = -10\text{ mA}$, $V_D = \pm 12.5\text{ V}$ $V_+ = 13.5\text{ V}$, $V_- = -13.5\text{ V}$	Room Full	20		35 45		35 45	Ω	
Switch Off Leakage Current	$I_{S(off)}$	$V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_D = \pm 15.5\text{ V}$ $V_S = \pm 15.5\text{ V}$	Room	-0.1	-0.25	0.25	-0.25	0.25	nA	
			Full		-20	20	-5	5		
	$I_{D(off)}$		Room Full	-0.1	-0.25 -20	0.25 20	-0.25 -5	0.25 5		
Channel Off Leakage Current	$I_{D(on)}$	$V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_S = V_D = \pm 15.5\text{ V}$	DG417	-0.4	-0.4	0.4	-0.4	0.4	nA	
			DG418	Room Full		-40	40	-10		10
			DG419	Room Full	-0.4	-0.75 -60	0.75 60	-0.75 -12		0.75 12
Digital Control										
Input Current V_{IN} Low	I_{IL}		Full	0.005	-0.5	0.5	-0.5	0.5	μA	
Input Current V_{IN} High	I_{IH}		Full	0.005	-0.5	0.5	-0.5	0.5	μA	
Dynamic Characteristics										
Turn-On Time	t_{ON}	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_S = \pm 10\text{ V}$	DG417 DG418	Room Full	100		175 250		175 250	ns
Turn-Off Time	t_{OFF}	See Switching Time Test Circuit	DG417 DG418	Room Full	60		145 210		145 210	
Transition Time	t_{TRANS}	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = \pm 10\text{ V}$, $V_{S2} = \pm 10\text{ V}$	DG419	Room Full			175 250		175 250	
Break-Before-Make Time Delay (DG403)	t_D	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ $V_{S1} = V_{S2} = \pm 10\text{ V}$	DG419	Room	13	5		5		
Charge Injection	Q	$C_L = 10\text{ nF}$, $V_{gen} = 0\text{ V}$, $R_{gen} = 0\ \Omega$		Room	60					pC

SPECIFICATIONS ^a									
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}$, $V_- = -15\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Dynamic Characteristics									
Source Off Capacitance	$C_{S(off)}$	$f = 1\text{ MHz}$, $V_S = 0\text{ V}$	Room	8					pF
Drain Off Capacitance	$C_{D(off)}$		DG417 DG418	Room	8				
Channel On Capacitance	$C_{D(on)}$	$f = 1\text{ MHz}$, $V_S = 0\text{ V}$	DG417 DG418	Room	30				
			DG419	Room	35				
Power Supplies									
Positive Supply Current	I_+	$V_+ = 16.5\text{ V}$, $V_- = -16.5\text{ V}$ $V_{IN} = 0\text{ or }5\text{ V}$	Room Full	0.001		1 5		1 5	μA
Negative Supply Current	I_-		Room Full	- 0.001	- 1 - 5		- 1 - 5		
Logic Supply Current	I_L		Room Full	0.001		1 5		1 5	
Ground Current	I_{GND}		Room Full	- 0.0001	- 1 - 5		- 1 - 5		

SPECIFICATIONS ^a for Unipolar Supplies									
Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 12\text{ V}$, $V_- = 0\text{ V}$ $V_L = 5\text{ V}$, $V_{IN} = 2.4\text{ V}$, 0.8 V^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V_{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	$R_{DS(on)}$	$I_S = -10\text{ mA}$, $V_D = 3.8\text{ V}$ $V_+ = 10.8\text{ V}$	Room	40					Ω
Dynamic Characteristics									
Turn-On Time	t_{ON}	$R_L = 300\ \Omega$, $C_L = 35\text{ pF}$, $V_S = 8\text{ V}$ See Switching Time Test Circuit	Room	110					ns
Turn-Off Time	t_{OFF}		Room	40					
Break-Before-Make Time Delay	t_D	DG419 Only $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$	Room	60					
Charge Injection	Q	$C_L = 10\text{ nF}$, $V_{gen} = 0\text{ V}$, $R_{gen} = 0\ \Omega$	Room	5					pC
Power Supplies									
Positive Supply Current	I_+	$V_+ = 13.2\text{ V}$, $V_L = 5.25\text{ V}$ $V_{IN} = 0\text{ or }5\text{ V}$	Room	0.001					μA
Negative Supply Current	I_-		Room	- 0.001					
Logic Supply Current	I_L		Room	0.001					
Ground Current	I_{GND}		Room	- 0.001					

Notes:

- Refer to Process Option Flowchart.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



R_{DS(on)} vs. V_D and Supply Voltage



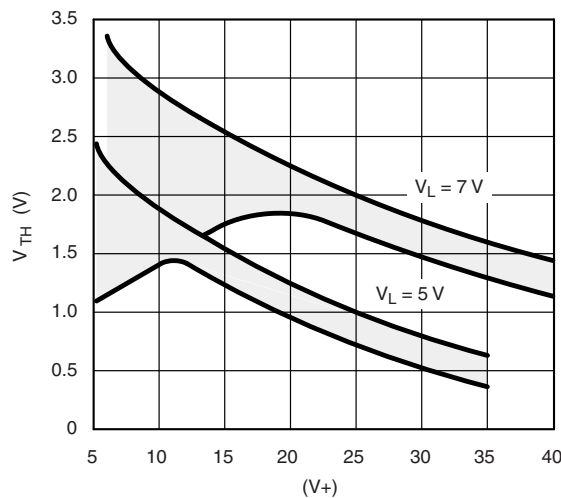
R_{DS(on)} vs. Temperature



Leakage Currents vs. Analog Voltage



Drain Charge Injection



Input Switching Threshold vs. Supply Voltages

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Switching Time vs. Temperature



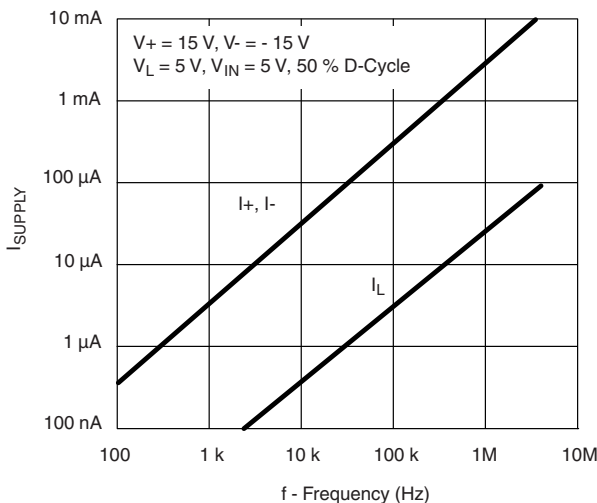
Crosstalk and Off Isolation vs. Frequency



Switching Time vs. Supply Voltages



Switching Time vs. V_+



Power Supply Currents vs. Switching Frequency



Supply Current vs. Temperature

TEST CIRCUITS

V_O is the steady state output with the switch on.



C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 2. Switching Time (DG417, DG418)



C_L (includes fixture and stray capacitance)



Figure 3. Break-Before-Make (DG419)



C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



Figure 4. Transition Time (DG419)

TEST CIRCUITS

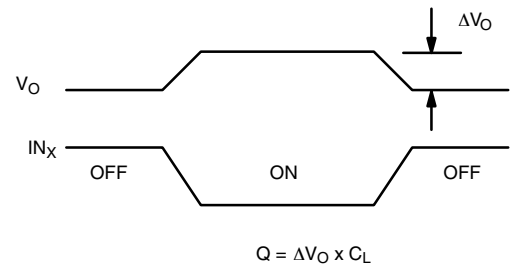
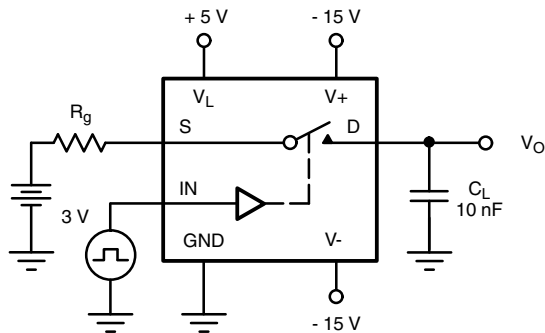


Figure 5. Charge Injection



Figure 6. Crosstalk (DG419)

$$X_{\text{TALK Isolation}} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

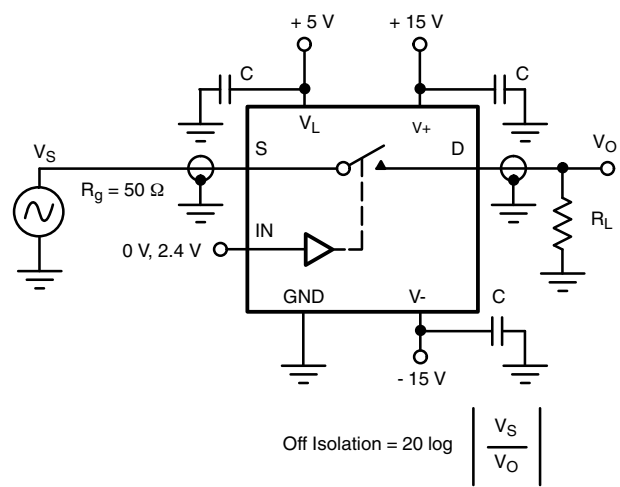


Figure 7. Off Isolation

$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

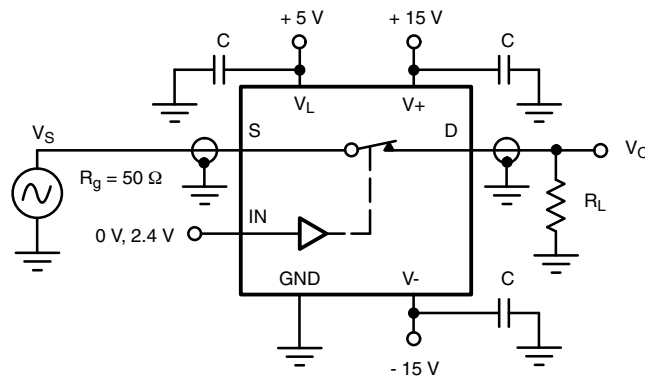
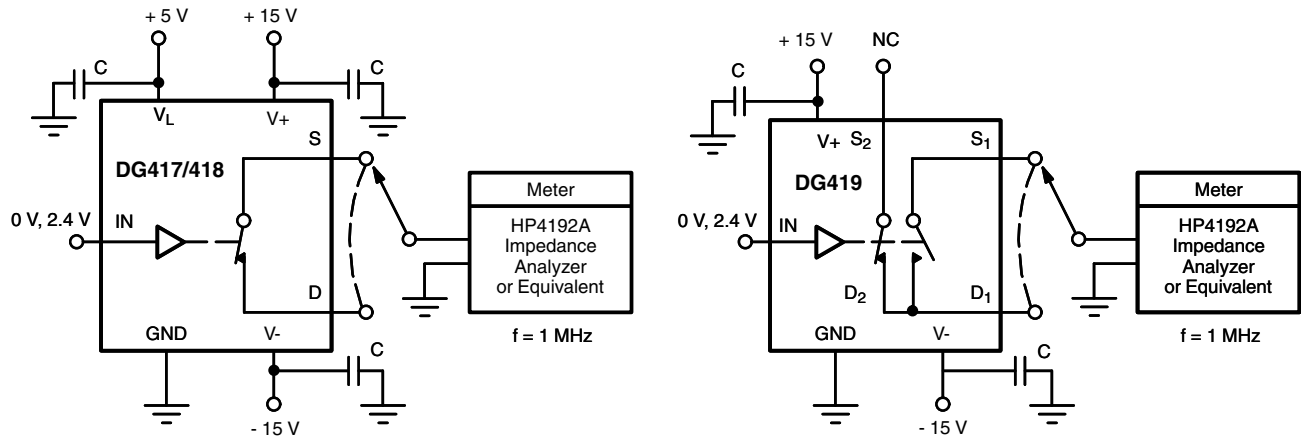


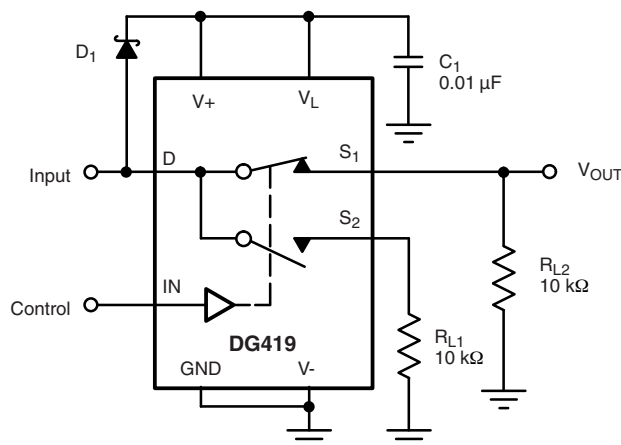
Figure 8. Insertion Loss

TEST CIRCUITS

Figure 9. Source/Drain Capacitances
APPLICATIONS
Switched Signal Powers Analog Switch

The analog switch in Figure 10 derives power from its input signal, provided the input signal amplitude exceeds 4 V and its frequency exceeds 1 kHz.

This circuit is useful when signals have to be routed to either of two remote loads. Only three conductors are required: one for the signal to be switched, one for the control signal and a common return.

A positive input pulse turns on the clamping diode D_1 and charges C_1 . The charge stored on C_1 is used to power the chip; operation is satisfactory because the switch requires less than $1 \mu\text{A}$ of stand-by supply current. Loading of the signal source is imperceptible. The DG419's on-resistance is a low 100Ω for a 5 V input signal.


Figure 10. Switched Signal Powers Remote SPDT Analog Switch

APPLICATIONS

Micropower UPS Transfer Switch

When V_{CC} drops to 3.3 V, the DG417 changes states, closing SW_1 and connecting the backup cell, as shown in Figure 10. D_1 prevents current from leaking back towards the rest of the circuit. Current consumption by the CMOS analog switch is around 100 pA; this ensures that most of the power available is applied to the memory, where it is really needed. In the stand-by mode, hundreds of A are sufficient to retain memory data.

When the 5 V supply comes back up, the resistor divider senses the presence of at least 3.5 V, and causes a new change of state in the analog switch, restoring normal operation.

Programmable Gain Amplifier

The DG419, as shown in figure 11, allows accurate gain selection in a small package. Switching into virtual ground reduces distortion caused by $R_{DS(on)}$ variation as a function of analog signal amplitude.

GaAs FET Driver

The DG419, as shown in figure 12 may be used as a GaAs FET driver. It translates a TTL control signal into - 8 V, 0 V level outputs to drive the gate.

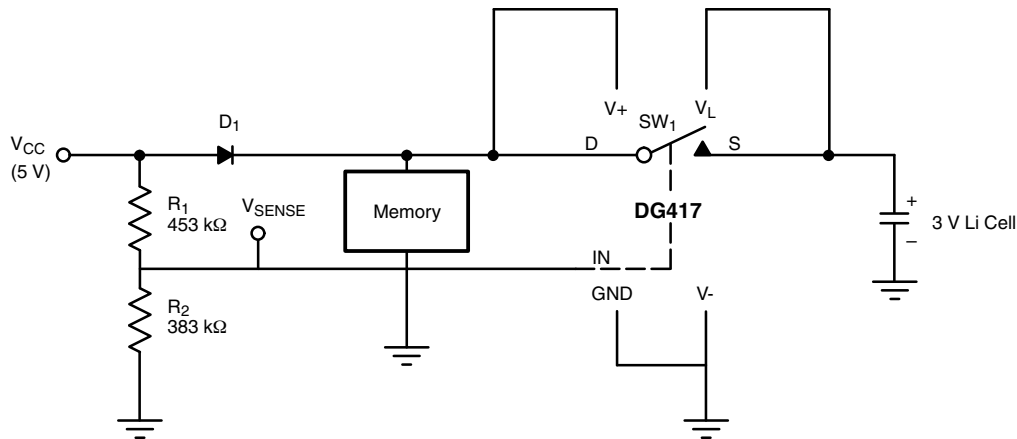


Figure 11. Micropower UPS Circuit

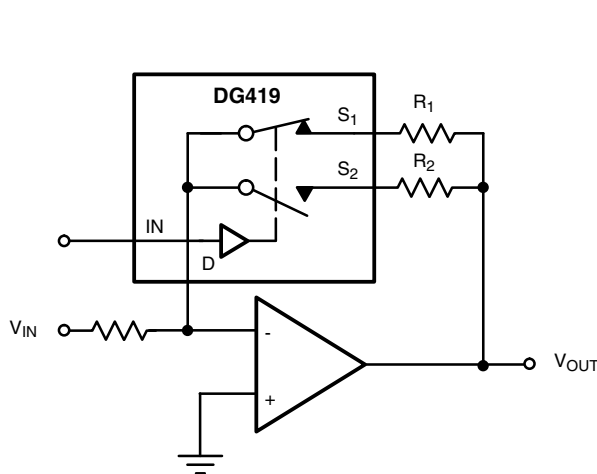


Figure 12. Programmable Gain Amplifier

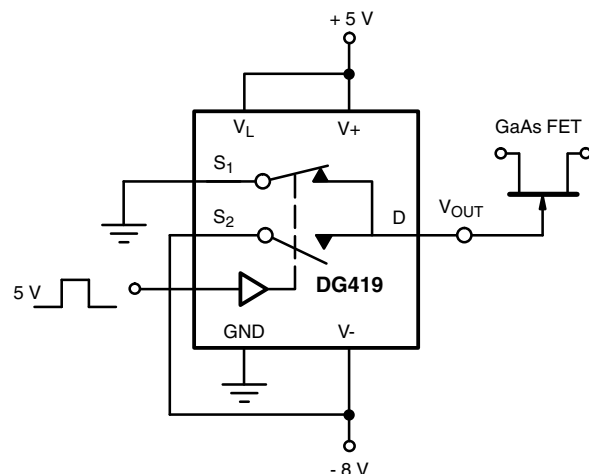


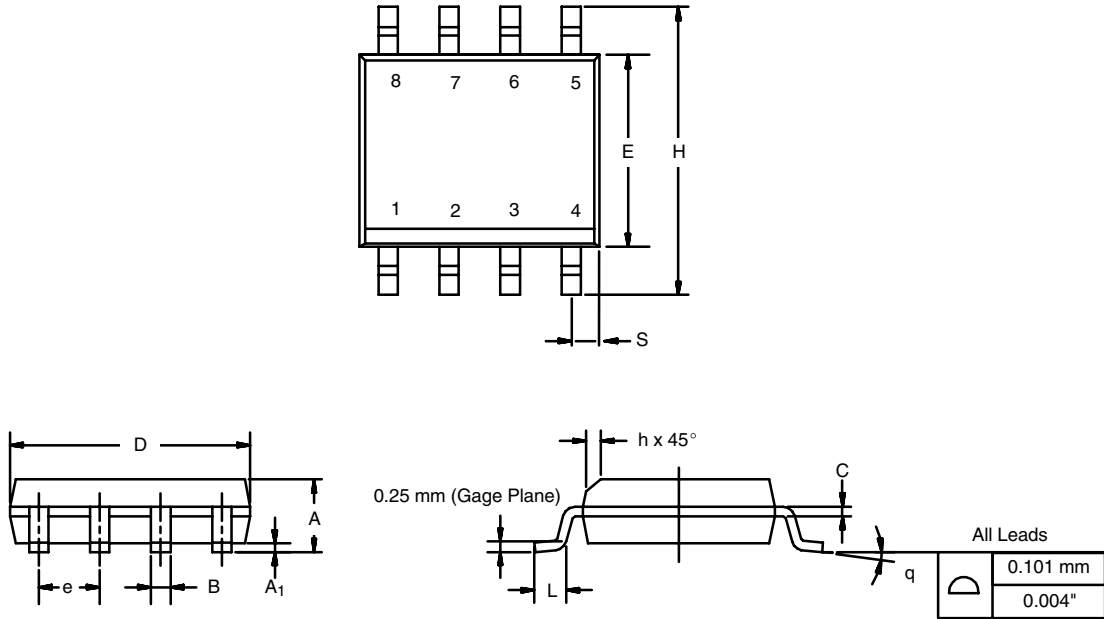
Figure 13. GaAs FET Driver

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppq?70051.



SOIC (NARROW): 8-LEAD

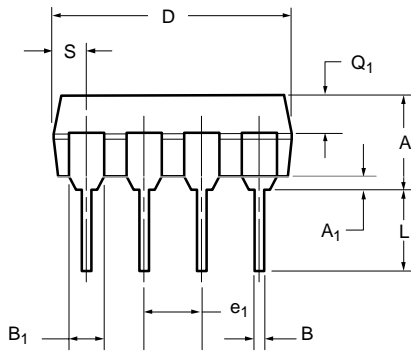
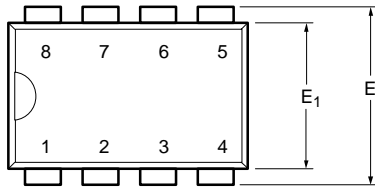
JEDEC Part Number: MS-012



DIM	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.35	0.51	0.014	0.020
C	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498				



PDIP: 8-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	9.02	10.92	0.355	0.430
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.76	1.65	0.030	0.065

ECN: S-03946—Rev. E, 09-Jul-01
DWG: 5478

NOTE: End leads may be half leads.

RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.